NSN 5961-00-175-9206

Transistor - Page 1 of 2



View Online at https://aerobasegroup.com/nsn/5961-00-175-9206 **Inclosure Material:** Metal and ceramic **Overall Length:** 0.270 inches **Overall Height:** 0.320 inches **Overall Diameter:** 0.360 inches **Mounting Facility Quantity: Internal Configuration:** Junction contact **Electrode Internally-electrically Connected To Case:** Emitter **Mounting Method:** Threaded stud **Features Provided:** Hermetically sealed case **Thread Size:** 0.190 inches **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 90.0 breakdown voltage, collector-to-base, emitter open **Current Rating Per Characteristic:** 3.30 amperes all primaries **Power Rating Per Characteristic:** 70.0 watts small-signal input power, common-collector **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius junction **Special Features:** Junction pattern arrangement: npn **Thread Series Designator:** Unf **Terminal Type And Quantity:** 3 pin Shelf Life: N/a **Unit Of Measure:**

Demilitarization:

No

NSN 5961-00-175-9206 Transistor - Page 2 of 2



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